

Absolute Maximum Ratings

Symbol	Parameter	Value	Units
P_{pk}	Peak Pulse Power ($t_p=8/20\mu s$)	250	W
T_{OP}	Operating Temperature	-40 to 150	°C
T_{STOR}	Storage Temperature	-55 to 150	°C

Notes:

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the component. This is a stress only rating and operation of the component at these or any other conditions above those indicated in the operational sections of this specification is not implied.

AQHV12 Electrical Characteristics ($T_{OP}=25^\circ C$)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}	$I_R=1\mu A$			12.0	V
Breakdown Voltage	V_{BR}	$I_R=1mA$	13.3	14.3		V
Reverse Leakage Current	I_{LEAK}	$V_R=12V$		5	50	nA
Clamp Voltage ¹	V_C	$I_{PP}=1A, t_p=8/20\mu s, I/O$ to GND		16.5	20	V
		$I_{PP}=10A, t_p=8/20\mu s, I/O$ to GND		23.5	26	V
Dynamic Resistance ²	R_{DYN}	TLP, $t_p=100ns, I/O$ to GND		0.22		Ω
Peak Pulse Current	I_{PP}	$t_p=8/20\mu s$			10.0	A
ESD Withstand Voltage ¹	V_{ESD}	IEC 61000-4-2 (Contact Discharge)	± 30			kV
		IEC 61000-4-2 (Air Discharge)	± 30			kV
Diode Capacitance ¹	$C_{I/O-GND}$	Reverse Bias=0V, f=1MHz		55.5	60	pF

AQHV15 Electrical Characteristics ($T_{OP}=25^\circ C$)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}	$I_R=1\mu A$			15	V
Breakdown Voltage	V_{BR}	$I_R=1mA$	16.7	18.7		V
Reverse Leakage Current	I_{LEAK}	$V_R=15V$		5	50	nA
Clamp Voltage ¹	V_C	$I_{PP}=1A, t_p=8/20\mu s, I/O$ to GND		21.5	25	V
		$I_{PP}=7A, t_p=8/20\mu s, I/O$ to GND		30	35	V
Dynamic Resistance ²	R_{DYN}	TLP, $t_p=100ns, I/O$ to GND		0.25		Ω
Peak Pulse Current	I_{PP}	$t_p=8/20\mu s$			7.0	A
ESD Withstand Voltage ¹	V_{ESD}	IEC 61000-4-2 (Contact Discharge)	± 30			kV
		IEC 61000-4-2 (Air Discharge)	± 30			kV
Diode Capacitance ¹	$C_{I/O-GND}$	Reverse Bias=0V, f=1MHz		43	46	pF

AQHV24 Electrical Characteristics ($T_{OP}=25^\circ C$)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}	$I_R=1\mu A$			24	V
Breakdown Voltage	V_{BR}	$I_R=1mA$	26.7	28.7		V
Reverse Leakage Current	I_{LEAK}	$V_R=24V$		5	50	nA
Clamp Voltage ¹	V_C	$I_{PP}=1A, t_p=8/20\mu s, I/O$ to GND		33	38	V
		$I_{PP}=5A, t_p=8/20\mu s, I/O$ to GND		46.5	52	V
Dynamic Resistance ²	R_{DYN}	TLP, $t_p=100ns, I/O$ to GND		0.35		Ω
Peak Pulse Current	I_{PP}	$t_p=8/20\mu s$			5	A
ESD Withstand Voltage ¹	V_{ESD}	IEC 61000-4-2 (Contact Discharge)	± 25			kV
		IEC 61000-4-2 (Air Discharge)	± 30			kV
Diode Capacitance ¹	$C_{I/O-GND}$	Reverse Bias=0V, f=1MHz		30	32	pF

AQHV36 Electrical Characteristics (T_{OP}=25°C)

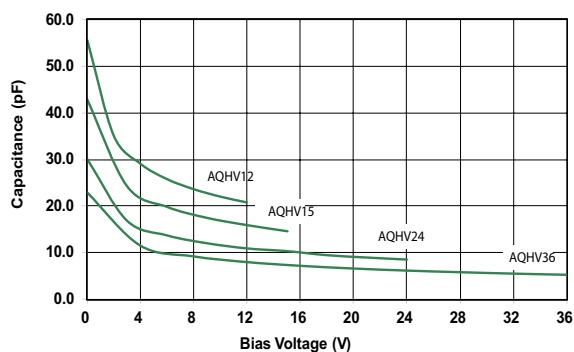
Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V _{RWM}	I _R =1μA			36	V
Breakdown Voltage	V _{BR}	I _R =1mA	40	42.4		V
Reverse Leakage Current	I _{LEAK}	V _R =36V		5	50	nA
Clamp Voltage ¹	V _C	I _{PP} =1A, t _p =8/20μs, I/O to GND		49.5	55	V
		I _{PP} =3A, t _p =8/20μs, I/O to GND		52.5	58	V
Dynamic Resistance ²	R _{DYN}	TLP, t _p =100ns, I/O to GND		1.15		Ω
Peak Pulse Current	I _{PP}	t _p =8/20μs			3	A
ESD Withstand Voltage ¹	V _{ESD}	IEC 61000-4-2 (Contact Discharge)	±15			kV
		IEC 61000-4-2 (Air Discharge)	±20			kV
Diode Capacitance ¹	C _{VO-GND}	Reverse Bias=0V, f=1MHz		23	25	pF

Note:

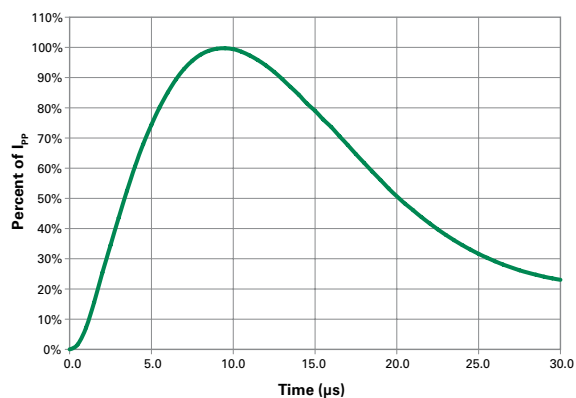
¹ Parameter is guaranteed by design and/or component characterization.

² Transmission Line Pulse (TLP) with 100ns width, 2ns rise time, and average window t1=70ns to t2= 90ns

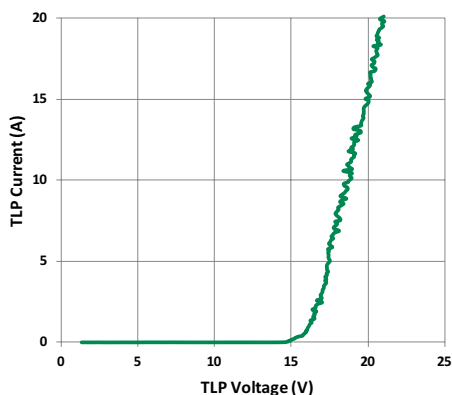
Capacitance vs. Reverse Bias



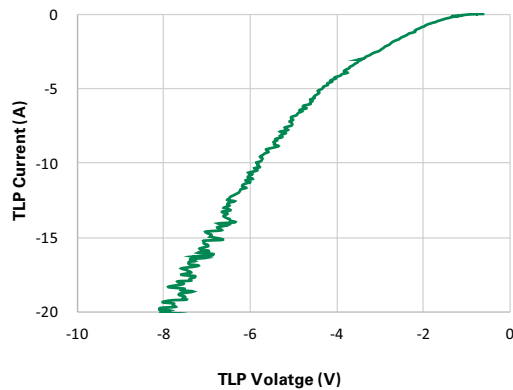
8/20μs Pulse Waveform



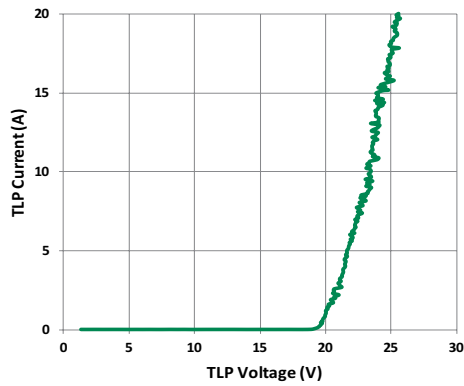
AQHV12 Positive Transmission Line Pulsing (TLP) Plot



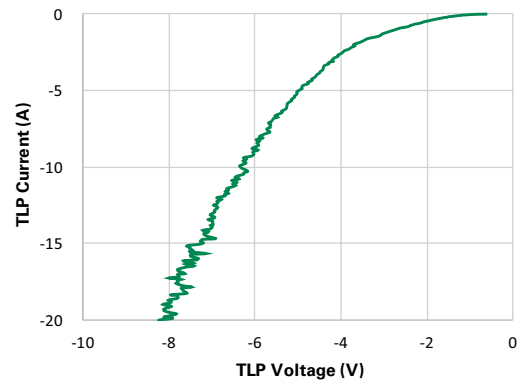
AQHV12 Negative Transmission Line Pulsing (TLP) Plot



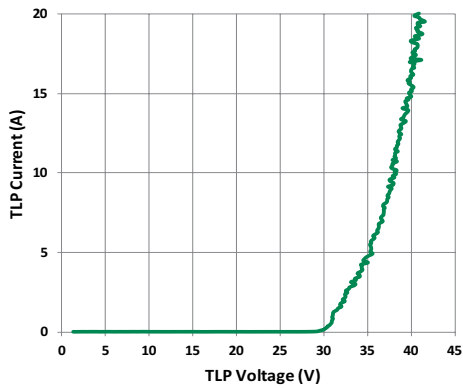
AQHV15 Positive Transmission Line Pulsing (TLP) Plot



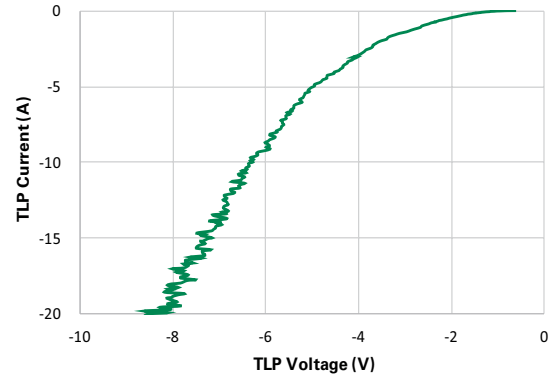
AQHV15 Negative Transmission Line Pulsing(TLP) Plot



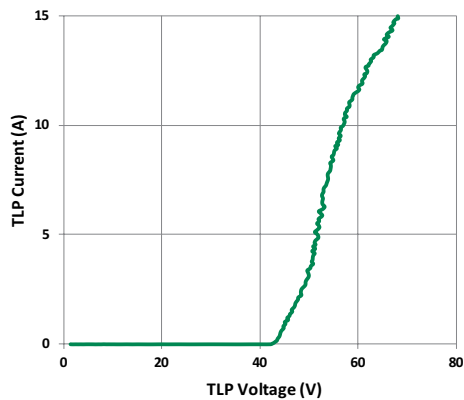
AQHV24 Positive Transmission Line Pulsing (TLP) Plot



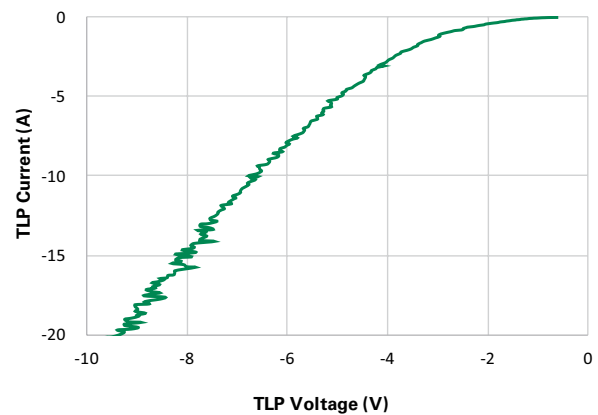
AQHV24 Negative Transmission Line Pulsing(TLP) Plot



AQHV36 Positive Transmission Line Pulsing(TLP) Plot



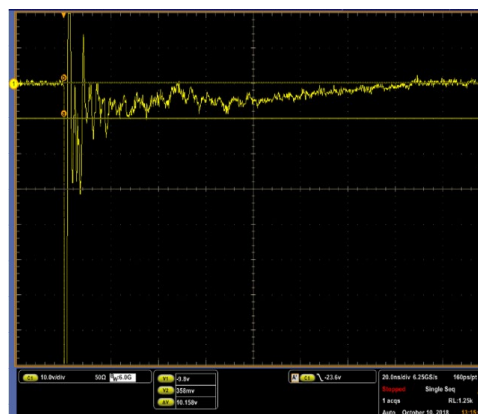
AQHV36 Negative Transmission Line Pulsing(TLP) Plot



AQHV12 +8kV Contact ESD Clamping Voltage



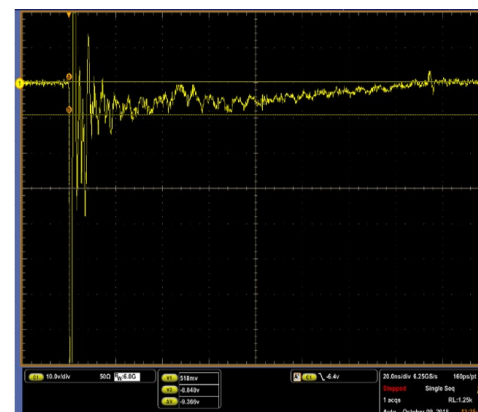
AQHV12 -8kV Contact ESD Clamping Voltage



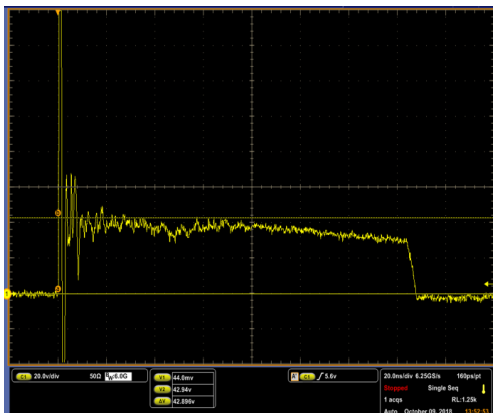
AQHV15 +8kV Contact ESD Clamping Voltage



AQHV15 -8kV Contact ESD Clamping Voltage



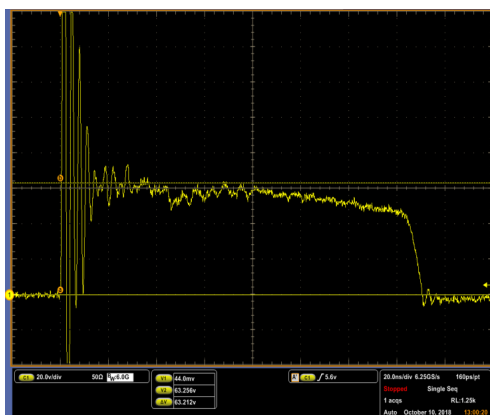
AQHV24 +8kV Contact ESD Clamping Voltage



AQHV24 -8kV Contact ESD Clamping Voltage



AQHV36 +8kV Contact ESD Clamping Voltage

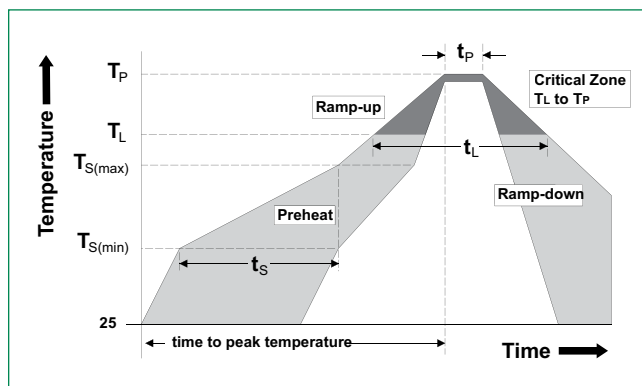


AQHV36 -8kV Contact ESD Clamping Voltage

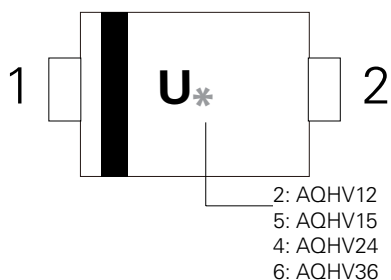


Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	-Temperature Min ($T_{s(min)}$)	150°C
	-Temperature Max ($T_{s(max)}$)	200°C
	-Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus) Temp (T_L) to peak		3°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/second max
Reflow	-Temperature (T_L) (Liquidus)	217°C
	-Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		260°C



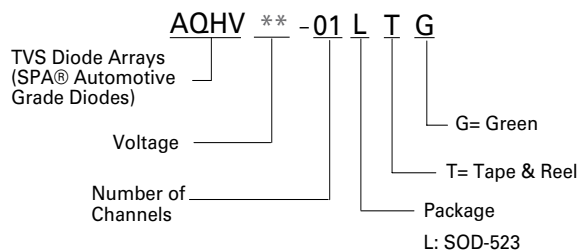
Part Marking System



Product Characteristics

Lead Plating	Matte Tin
Lead Material	Copper Alloy
Substrate Material	Silicon
Body Material	Molded Compound
Flammability	UL Recognized compound meeting flammability rating V-0

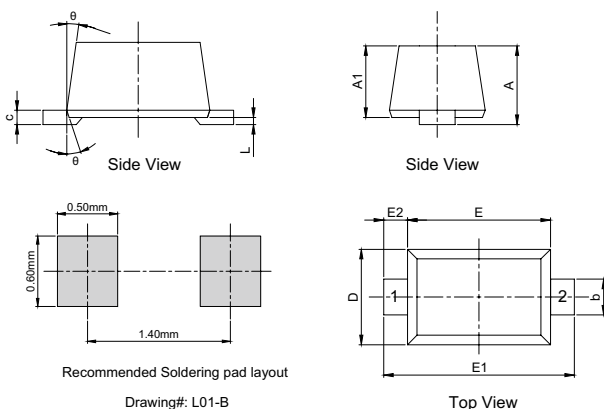
Part Numbering System



Ordering Information

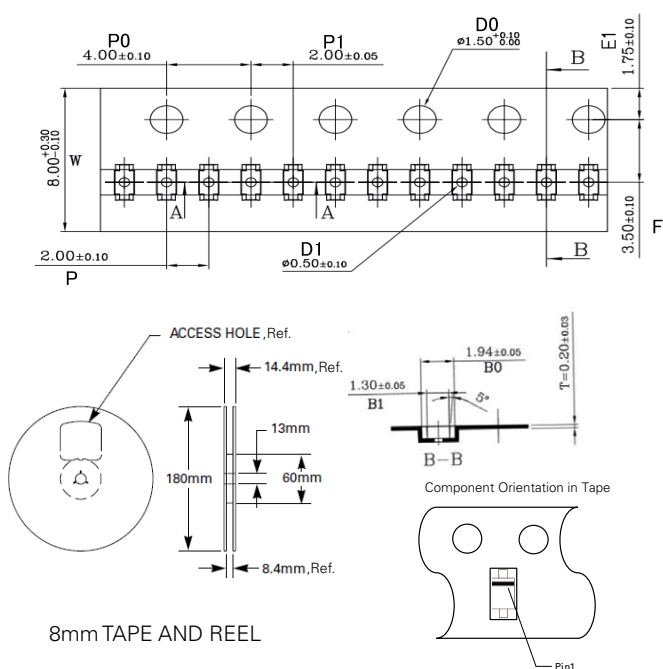
Part Number	Package	Min. Order Qty.
AQHV12-01LTG	SOD-523	5000
AQHV15-01LTG		
AQHV24-01LTG		
AQHV36-01LTG		

Package Dimensions — SOD-523



Symbol	Millimeters		Inches	
	Min	Max	Min	Max
A	0.51	0.77	0.020	0.030
A1	0.50	0.70	0.020	0.028
b	0.25	0.35	0.010	0.014
c	0.08	0.15	0.003	0.006
D	0.70	0.90	0.028	0.035
E	1.10	1.30	0.043	0.051
E1	1.50	1.70	0.059	0.067
E2	0.20 REF		0.001 REF	
L	0.01	0.07	0.000	0.003
θ	7° REF		7° REF	

Embossed Carrier Tape & Reel Specification — SOD-523



Symbol	Millimeters		Inches	
	Min	Max	Min	Max
A0	0.91	1.01	0.036	0.040
B0	1.89	1.99	0.074	0.078
D0	1.50	1.60	0.059	0.063
D1	0.40	0.60	0.016	0.024
E1	1.65	1.85	0.065	0.073
F	3.40	3.60	0.134	0.142
P0	3.90	4.10	0.154	0.161
P	1.90	2.10	0.075	0.083
P1	1.95	2.05	0.077	0.081
K0	0.68	0.78	0.027	0.031
T	0.17	0.23	0.007	0.009
W	7.90	8.30	0.311	0.327

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